NSN 5961-01-074-9721

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-074-9721 **Inclosure Material:** Ceramic or plastic **Overall Length:** 0.785 inches **Terminal Length:** 0.100 inches **Overall Width:** 0.250 inches **Electrode Internally-electrically Connected To Case: Emitter Mounting Method: Terminal Terminal Circle Diameter:** 0.050 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 collector to emitter voltage, dc and 70.0 collector to base voltage, dc and 6.0 emitter to base, rms **Current Rating Per Characteristic:** 1.50 amperes collector current, dc universal **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 300.0 degrees celsius junction **Terminal Type And Quantity:** 14 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No